



10A, 100V - 200V Dual Common Cathode Schottky Rectifiers

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21







MECHANICAL DATA

Case: TO-263AB (D²PAK)

Molding compound, UL flammability classification rating 94V-0

Moisture sensitivity level: level 1, per J-STD-020 Part no. with suffix "H" means AEC-Q101 qualified

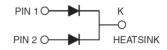
Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

Polarity: As marked

Weight: 1.4 g (approximately)

TO-263AB (D²PAK)



PARAMETER	SYMBOL	MBRS	MBRS	MBRS	UNIT
I ANAIVIETEN	STWBOL	10H100CT	10H150CT	10H200CT	0.4
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V
Maximum RMS voltage	V_{RMS}	70	105	140	V
Maximum DC blocking voltage	V_{DC}	100	150	200	V
Maximum average forward rectified current	I _{F(AV)}		10		Α
Peak repetitive forward current (Rated VR, Square wave, 20KHz)	I _{FRM}	10		А	
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	120		А	
Peak repetitive reverse surge current (Note 1)	I _{RRM}		1	0.5	Α
Maximum instantaneous forward voltage (Note 2)					
I _F = 5 A, T _J =25°C	V _F	0.85	0.88 0.75 0.97 0.85		V
I _F = 5 A, T _J =125°C		0.75			
I _F = 10 A, T _J =25°C		0.95			
I _F = 10 A, T _J =125°C		0.85			
Maximum reverse current @ rated V _R	1	5			μA
T _J =125°C	I _R	1			mA
Voltage rate of change (Rated V _R)	dV/dt	10000			V/µs
Typical thermal resistance	$R_{ heta JC}$	R _{θJC} 3.5			°C/W
Operating junction temperature range	TJ	- 55 to +175		°C	
Storage temperature range	T _{STG}	- 55 to +175		°C	

Note 1: $tp = 2.0 \mu s$, 1.0KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle

Document Number: DS_D1309058

Taiwan Semiconductor

ORDERING INFORMATION					
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX ^(*)	PACKAGE	PACKING
MBRS10HxxxCT	П	RN	G	D ² PAK	800 / 13" Paper reel
(Note 1)	11	MN	G	DPAK	800 / 13" Plastic reel

Note 1: "xx" defines voltage from 100V (MBRS10H100CT) to 200V (MBRS10H200CT)

^{*:} Optional available

EXAMPLE					
PREFERRED P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
MBRS10H100CTHRNG	MBRS10H100CT	Н	RN	G	AEC-Q101 qualified Green compound

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

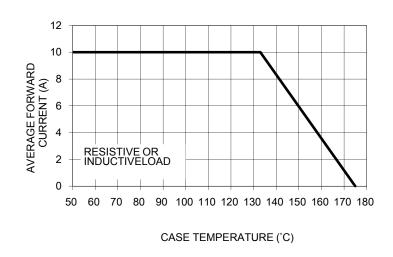


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

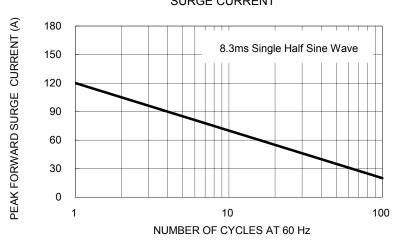


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

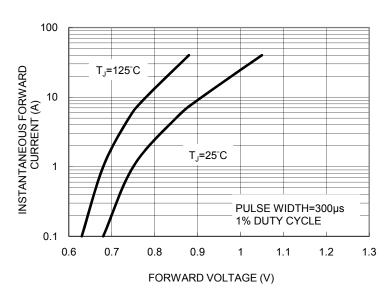
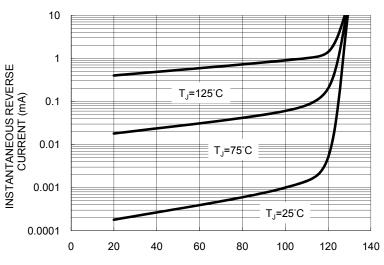


FIG. 4 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)



Taiwan Semiconductor

FIG. 5 TYPICAL JUNCTION CAPACITANCE

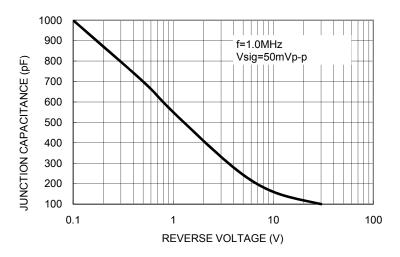
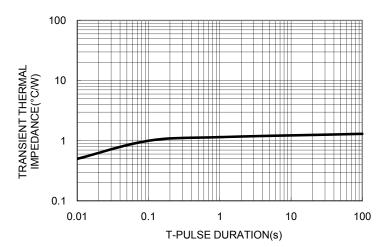
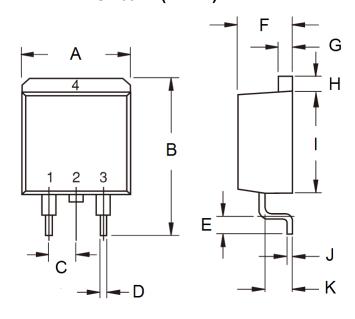


FIG. 6 TYPICAL TRANSIENT THERMAL IMPEDANCE

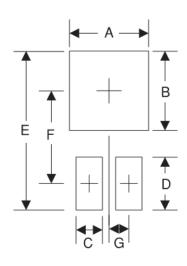


PACKAGE OUTLINE DIMENSIONS TO-263AB (D²PAK)



DIM.	Unit	(mm)	Unit (inch)	
Dilvi.	Min	Max	Min	Max
Α	-	10.5	-	0.413
В	14.60	15.88	0.575	0.625
С	2.41	2.67	0.095	0.105
D	0.68	0.94	0.027	0.037
Е	2.29	2.79	0.090	0.110
F	4.44	4.70	0.175	0.185
G	1.14	1.40	0.045	0.055
Н	1.14	1.40	0.045	0.055
1	8.25	9.25	0.325	0.364
J	0.36	0.53	0.014	0.021
K	2.03	2.79	0.080	0.110

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.8	0.425
В	8.3	0.327
С	1.1	0.043
D	3.5	0.138
E	16.9	0.665
Ŀ	9.5	0.374
G	2.5	0.098

MARKING DIAGRAM



P/N = Specific Device Code G = Green Compound

YWW = Date Code F = Factory Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

Document Number: DS_D1309058 Version: I15

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRA140TRPBF MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573